# NSN 5961-01-038-0812

Semiconductor Device Set - Page 1 of 1



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Glass all semiconductor device diode

### **Overall Length:**

0.300 inches all semiconductor device diode

### **Terminal Length:**

1.500 inches all semiconductor device diode

#### **Overall Diameter:**

0.092 inches all semiconductor device diode and 0.104 inches all semiconductor device diode

### **Internal Configuration:**

Junction contact all semiconductor device diode

#### **Internal Junction Configuration:**

Pn all semiconductor device diode

### **Component Function Relationship:**

Matched

### **Component Name And Quantity:**

2 semiconductor device diode

### **Mounting Method:**

Terminal all semiconductor device diode

### **Features Provided:**

Hermetically sealed case

### **Semiconductor Material:**

Silicon all semiconductor device diode

### Voltage Rating In Volts Per Characteristic:

5.0 reverse voltage, peak all semiconductor device diode

### **Current Rating Per Characteristic:**

50.00 milliamperes forward current, average absolute all semiconductor device diode

### **Power Rating Per Characteristic:**

100.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode

### **Maximum Operating Tempurature Per Measurement Point:**

150.0 degrees celsius ambient air all semiconductor device diode

### **Terminal Type And Quantity:**

2 uninsulated wire lead all semiconductor device diode

### Shelf Life:

N/a

### **Unit Of Measure:**

## **Demilitarization:**

No

### Fiig:

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